Thin Films E5125 Learning goals

Student can describe the following concepts and compare them with each other.

Surface engineering and vacuum

- Surface phenomena
 - o Surface structure, energy, reconstruction
 - Adsorption&desorption
 - o Surface diffusion
- Energetic ion-surface interactions
- Vacuum
 - Vacuum system
 - Pressure units
 - Residual gas
 - o Formation time of a monolayer on surface
 - o Pumps
 - Vacuum gauges

PVD

- Principle ideas of palsma: glow discharge and arc
- Sputter mechanism
- Thorton diagram: microstructure as function of ion energy and substrate temperature
- Subplantation
- Residual stress
- Magnetron sputtering
- Pulsed MS (HIPIMS)
- Reactive sputtering
- Arc deposion
- Pulsed laser deposition

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Characterization

- Role of vacuum in characterization methods
- Thickness
- Residual stress
- ion beam characterization
 - o SIMS
 - o Rutherford Back Scattering (RBS), and Forward Recoil Spectroscopy
- X-ray spectroscopy
 - Glancing angle XRD
 - o X-ray reflection XRR
- XPS- ESCA
- RAMAN
- Indentation, nanoindentation

CVD/ALD

- Thermanl CVD process,
 - o Precursors
 - Mass transport
 - o Silicon growth
- Plasma assisted CVD
 - o Plasma enabling lower deposition temperature
 - Hydrogen content
 - o Reactor architectures
- ALD
 - o Growth process
 - o Process window
 - o Reactor architectures
 - Conformality
 - o Materials
- Applications

Other coating methods

- Electroplating
- Electroless deposition
- Spin coating
- Dip coating
- Langmuir-Blodgett method
- Sol-Gel
- Flame Spray